

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	voltage near less near than near reference	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:34
L2	0	(potential voltage) near less near than near reference	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:36
L3	217583	reference near (potential voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:36
L4	0	(potential voltage) near less near than near reference	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:36
L5	225	(substrate (well near region)) near reference near (potential voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:37
L6	89	5 and memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:50
L7	14	memory with (substrate (well near region)) near reference near (potential voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:42
L8	2069	memory with (substrate (well near region)) near (potential voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:53

L9	1681366	memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:50
L10	74634	writ\$3 near operat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:52
L11	60965	10 and 9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:52
L12	209	memory with ((substrate (well near region)) near (potential voltage)) with (source near (potential voltage))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:54
L13	107	12 and 10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/22 19:54